

isc N-Channel MOSFET Transistor

IXTP180N085T

• FEATURES

- Static drain-source on-resistance:
 $R_{DS(on)} \leq 5.5m\Omega @ V_{GS}=10V$
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATION

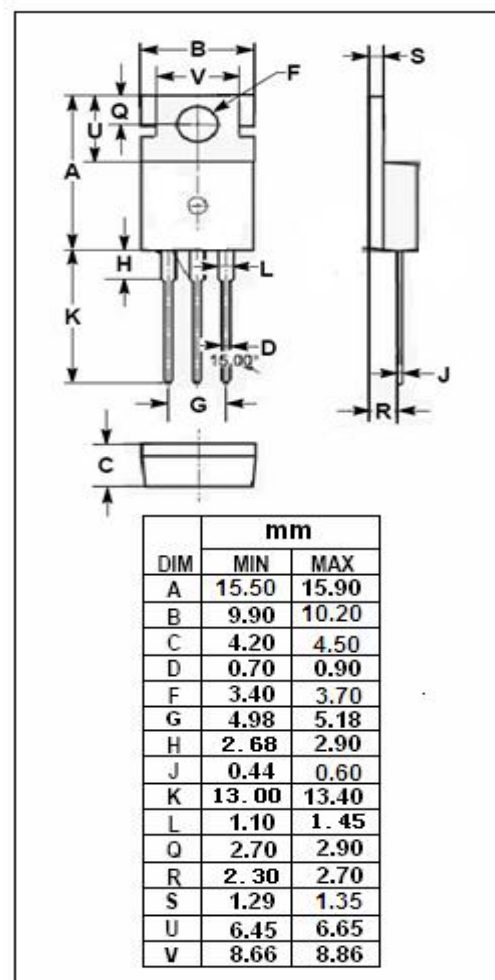
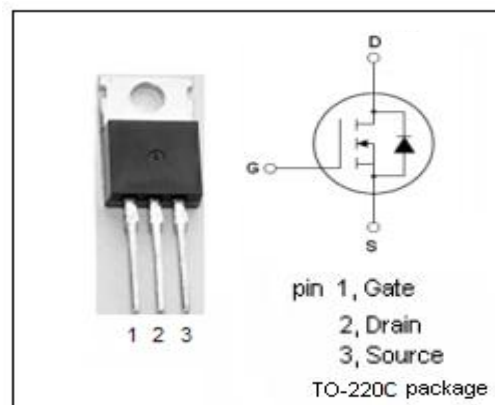
- DC/DC Converters
- High Current Switching Applications

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	85	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	180	A
I_{DM}	Drain Current-Single Pulsed	480	A
P_D	Total Dissipation @ $T_c=25^\circ C$	430	W
T_j	Operating Junction Temperature	-55~175	$^\circ C$
T_{stg}	Storage Temperature	-55~175	$^\circ C$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Junction-to-case thermal resistance	0.35	$^\circ C/W$



isc N-Channel MOSFET Transistor**IXTP180N085T****ELECTRICAL CHARACTERISTICS** $T_c=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V$; $I_D = 250\ \mu A$	85		V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$; $I_D = 250\ \mu A$	2.0	4.0	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V$; $I_D=25A$		5.5	$m\Omega$
I_{GSS}	Gate-Source Leakage Current	$V_{GS}= \pm 20V$; $V_{DS}=0V$		± 200	nA
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=V_{DSS}$; $V_{GS}=0V$		5	μA
		$V_{DS}=V_{DSS}$; $V_{GS}=0V$; $T_J=150^{\circ}\text{C}$		250	
V_{SD}	Diode forward voltage	$I_F=25A$; $V_{GS}=0V$		1.0	V

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